SCIENTIFIC **Reports**

OPEN Erratum: Strain-Engineered **Graphene Grown on Hexagonal Boron Nitride by Molecular Beam Epitaxy**

Alex Summerfield, Andrew Davies, Tin S. Cheng, Vladimir V. Korolkov, Yong Jin Cho, Christopher J. Mellor, C. Thomas Foxon, Andrei N. Khlobystov, Kenji Watanabe, Takashi Taniguchi, Laurence Eaves, Sergei V. Novikov & Peter H. Beton

Scientific Reports 6:22440; doi: 10.1038/srep22440; published online 01 March 2016; updated 02 June 2016

The following statement has been omitted from the 'Additional Information' section of the HTML version of this Article:

"Data Availability: The images and spectra on which this paper is based may be publicly accessed and are stored at 10.17639/nott.35".

The PDF version of this Article was correct at the time of publication.

This work is licensed under a Creative Commons Attribution 4.0 International License. The images or other third party material in this article are included in the article's Creative Commons license, unless indicated otherwise in the credit line; if the material is not included under the Creative Commons license, users will need to obtain permission from the license holder to reproduce the material. To view a copy of this license, visit http://creativecommons.org/licenses/by/4.0/